NSN 5961-01-156-7027

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Inclosure Material:

Metal

Overall Length:

1.470 inches

Overall Diameter:

0.847 inches

Internal Configuration:

Junction contact

Mounting Method:

Press fit

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

110.0 breakdown voltage, collector-to-base, emitter open and 110.0 collector to emitter reverse voltage and 3.6 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

20.00 amperes source cutoff current

Power Rating Per Characteristic:

320.0 watts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

4 ribbon

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0